Vishay Semiconductors

Hyperfast Rectifier, 30 A FRED Pt®



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PRODUCT SUMMARY						
Package	TO-247AD 3L					
I _{F(AV)}	30 A					
V _R	600 V					
V _F at I _F	1.4 V					
t _{rr} typ.	26 ns					
T _J max.	175 °C					
Diode variation	Single die					

FEATURES

- Low forward voltage drop
- Hyperfast soft recovery time
- 175 °C operating junction temperature
- Designed and qualified according to commercial qualification
- AEC-Q101 qualified, meets JESD 201 class 2 whisker test
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>

DESCRIPTION / APPLICATIONS

Hyperfast recovery rectifiers designed with optimized performance of forward voltage drop, hyperfast recovery time, and soft recovery.

The planar structure and the platinum doped life time control guarantee the best overall performance, ruggedness and reliability characteristics.

These devices are intended for use in PFC Boost stage in the AC/DC section of SMPS, inverters or as freewheeling diodes.

The extremely optimized stored charge and low recovery current minimize the switching losses and reduce over dissipation in the switching element and snubbers.

ABSOLUTE MAXIMUM RATINGS							
PARAMETER	SYMBOL	TEST CONDITIONS	MAX.	UNITS			
Repetitive peak reverse voltage	V _{RRM}		600	V			
Average rectified forward current	I _{F(AV)}	T _C = 112 °C	30				
Non-repetitive peak surge current	I _{FSM}	$T_C = 25$ °C, $t_p = 8.3$ ms half sine wave; connecting two anode pins	240	A			
Operating junction and storage temperatures	T _J , T _{Stg}		-55 to +175	°C			

ELECTRICAL SPECIFICATIONS (T _J = 25 °C unless otherwise specified)							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS	
Breakdown voltage, blocking voltage	V _{BR} , V _R	I _R = 100 μA	600	-	-		
Forward valtage	V	I _F = 30 A	-	2.0	2.65	V	
Forward voltage V _F	۷F	I _F = 30 A, T _J = 150 °C	-	1.4	1.8		
Povoroa loakago ourrant	1	$V_R = V_R$ rated	-	0.02	30		
Reverse leakage current I _R		$T_J = 150 \text{ °C}, V_R = V_R \text{ rated}$	-	-	300	μA	
Junction capacitance	CT	V _R = 600 V	-	20	-	pF	
Series inductance	L _S	Measured lead to lead 5 mm from package body	-	8.0	-	nH	

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RoHS

COMPLIANT

HALOGEN

FREE



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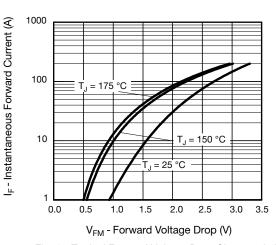
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DYNAMIC RECOVERY CHARACTERISTICS (T _J = 25 °C unless otherwise specified)									
PARAMETER	SYMBOL	TEST CO	MIN.	TYP.	MAX.	UNITS			
		$I_F = 1 \text{ A}, dI_F/dt = 50 \text{ A}/\mu \text{s}, V_R = 30 \text{ V}$		-	26	-			
Reverse recovery time	t _{rr}	T _J = 25 °C		-	26	-	ns		
		T _J = 125 °C		-	70	-			
Pook receivery ourrent	I _{RRM}	T _J = 25 °C	I _F = 30 A dI _F /dt = 200 A/μs V _R = 200 V	-	3.5	-	А		
Peak recovery current		T _J = 125 °C		-	7.6	-	A		
	0	T _J = 25 °C		-	50	-	nC		
Reverse recovery charge	Q _{rr}	T _J = 125 °C		-	280	-	nc		

THERMAL - MECHANICA	THERMAL - MECHANICAL SPECIFICATIONS							
PARAMETER	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNITS		
Maximum junction and storage temperature range	T _J , T _{Stg}		-55	-	175	°C		
Thermal resistance, junction to case	R _{thJC}		-	0.7	1.1	°C/W		
Thermal resistance, junction to ambient per leg	R _{thJA}	Typical socket mount	-	-	70			
Thermal resistance, case to heat sink	R _{thCS}	Mounting surface, flat, smooth, and greased	-	0.5	-			
Weight			-	5.5	-	g		
weight			-	0.2	-	oz.		
Mounting torque			1.2 (10)	-	2.4 (20)	kgf · cm (lbf · in)		
Marking device		Case style TO-247AD 3L		APH3	006LH			

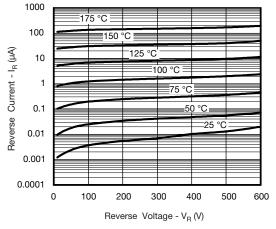
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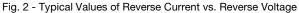
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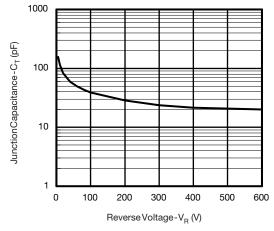
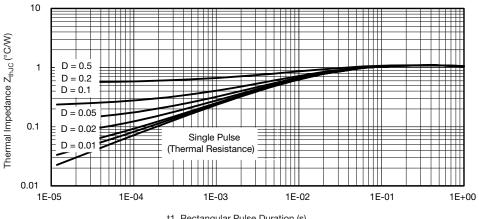
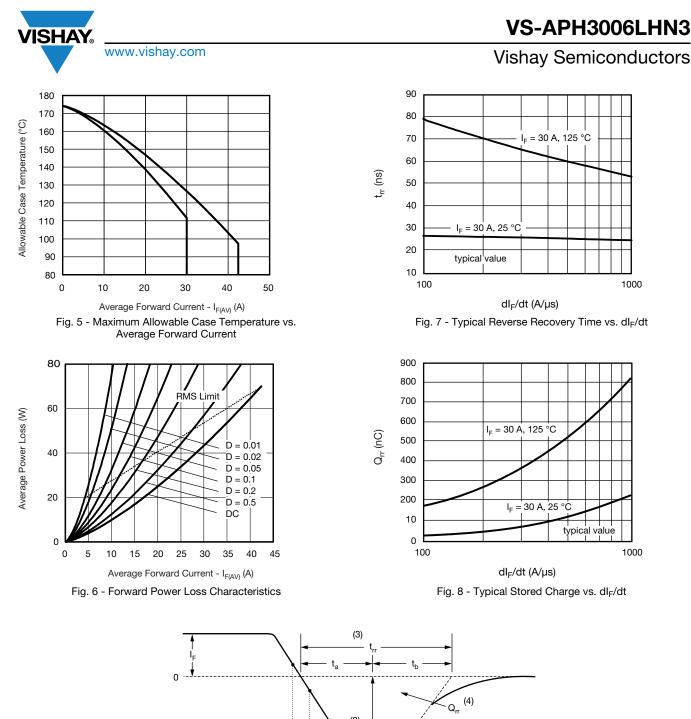


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage



t1, Rectangular Pulse Duration (s)

Fig. 4 - Max. Thermal Impedance Z_{thJC} Characteristics



(2) 0.5 I_{RRM} I_{RRM} dl_{(rec)M}/dt (5) 0.75 I_{RRM} (1) dl_F/dt (4) Q_{rr} - area under curve defined by t_{rr} (1) dl_F/dt - rate of change of current and I_{RRM} through zero crossing $Q_{rr} = \frac{t_{rr} \times I_{RRM}}{2}$ (2) I_{RRM} - peak reverse recovery current (3) t_{rr} - reverse recovery time measured (5) dI_{(rec)M}/dt - peak rate of change of current during $t_{\rm b}$ portion of $t_{\rm rr}$ from zero crossing point of negative going I_F to point where a line passing through 0.75 I_{RRM} and 0.50 I_{RRM}

extrapolated to zero current.

Fig. 9 - Reverse Recovery Waveform and Definitions

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ORDERING INFORMATION TABLE

Device code	VS-	Α	Ρ	Н	30	06	L	Н	N3
	1	2	3	4	5	6	7	8	9
	1 -	Visł	nay Sem	niconduc	ctors pro	oduct			
	2 - Circuit configuration:								
	A = single diode								
	3 -	3 - P = TO-247							
	4 -	H =	hyperfa	ist recov	ery time	Э			
	5 -	Cur	rent cod	le (30 =	30 A)				
	6 -	Volt	age coo	le (06 =	600 V)				
	7 - L = long lead								
	8 -	H =	AEC-Q	101 qua	lified				
	9 -			ntal digit en-free,		ompliar	nt, and t	otally le	ead (Pb

ORDERING INFORMATION (Example)						
PREFERRED P/N	QUANTITY PER TUBE	MINIMUM ORDER QUANTITY	PACKAGING DESCRIPTION			
VS-APH3006LHN3	25	500	Antistatic plastic tube			

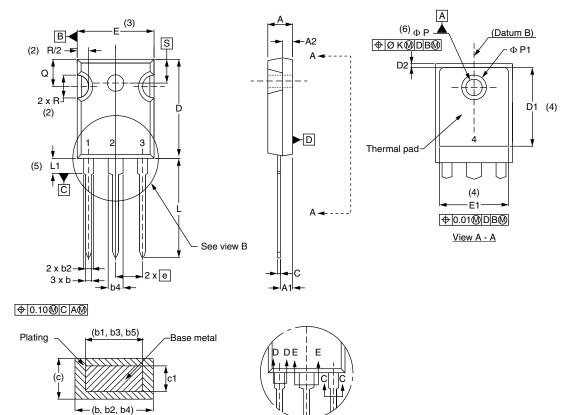
LINKS TO RELATED DOCUMENTS				
Dimensions	TO-247AD 3L	www.vishay.com/doc?95626		
Part marking information	TO-247AD 3L	www.vishay.com/doc?95007		



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TO-247AD 3L

DIMENSIONS in millimeters and inches



View B

SYMBOL	MILLIN	IETERS	INCHES		NOTES
STIVIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
А	4.65	5.31	0.183	0.209	
A1	2.21	2.59	0.087	0.102	
A2	1.50	2.49	0.059	0.098	
b	0.99	1.40	0.039	0.055	
b1	0.99	1.35	0.039	0.053	
b2	1.65	2.39	0.065	0.094	
b3	1.65	2.34	0.065	0.092	
b4	2.59	3.43	0.102	0.135	
b5	2.59	3.38	0.102	0.133	
с	0.38	0.89	0.015	0.035	
c1	0.38	0.84	0.015	0.033	
D	19.71	20.70	0.776	0.815	3
D1	13.08	-	0.515	-	4

(2, 52, 51) (4) Section C - C, D - D, E - E

SYMBOL	MILLIN	IETERS	INC	INCHES	
STNIBOL	MIN.	MAX.	MIN.	MAX.	NOTES
D2	0.51	1.30	0.020	0.051	
E	15.29	15.87	0.602	0.625	3
E1	13.46	-	0.53	-	
е	5.46	BSC	0.215	5 BSC	
ØК	0.2	254	0.0	010	
L	19.81	20.32	0.780	0.800	
L1	3.71	4.29	0.146	0.169	
ØР	3.56	3.66	0.14	0.144	
Ø P1	-	6.98	-	0.275	
Q	5.31	5.69	0.209	0.224	
R	4.52	5.49	0.178	0.216	
S	5.51 BSC		0.217	' BSC	

Notes

⁽¹⁾ Dimensioning and tolerancing per ASME Y14.5M-1994

(2) Contour of slot optional

- ⁽³⁾ Dimension D and E do not include mold flash. These dimensions are measured at the outermost extremes of the plastic body
- (4) Thermal pad contour optional with dimensions D1 and E1
- ⁽⁵⁾ Lead finish uncontrolled in L1
- (6) Ø P to have a maximum draft angle of 1.5 to the top of the part with a maximum hole diameter of 3.91 mm (0.154")
- ⁽⁷⁾ Outline conforms to JEDEC[®] outline TO-247 with exception of dimension A min., D, E min., Q min., S, and note 4

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